GOOD-ARK
SEMICONDUCTOR

HS2A thru HS2M

Ultrafast Recovery Rectifier
Reverse Voltage 50V-1000V Forward Current 1.5 A

Features

- Glass passivated junction chip
- For surface mount applications
- Low forward voltage drop
- Low profile package
- Built-in stain relief, ideal for automated placement
- Fast switching for high efficiency
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Weight: 0.003 ounce,0.093 gram

RoHS COMPLIANT



DO-214AA (SMB)

Applications

For use of general purpose rectifications in lighting, cellular phones, portable devices, power supplies and other consumer applications.

Maximum Ratings (T_A = 25°C unless otherwise noted)

Parameter	Symbol	HS2A	HS2B	HS2D	HS2F	HS2G	HS2J	HS2K	HS2M	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Boltage	V_{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Output Rectified Current	$I_{F(AV)}$	1.5								A
Peak Forward Surge Current (8.3 ms single half sine-wave superimposed on rated load)	I_{FSM}	50								A
Rating for Fusing (t<8.3ms)	I^2t	10								A^2sec
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150								°C

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Parameter	Test Conditions	Symbol	HS2A	HS2B	HS2D	HS2F	HS2G	HS2J	HS2K	HS2M	Unit
Maximum Instantaneous Forward Voltage	I_F=1.5A	V_F	1.0				1.3	1.7			V
Maximum DC Reverse Current at Rated DC Blocking Voltage	T_A=25°C T_A=125°C	I_R	5.0 100								μA
Maximum Reverse Recovery Time	I_F=0.5A,I_R=1.0A, I_{RR}=0.25A	t_{rr}	50					75			ns
Typical Junction Capacitance	4.0 V, 1 MHz	C_J	50					30			pF

Thermal Characteristics

Parameter	Symbol	HS2A	HS2B	HS2D	HS2F	HS2G	HS2J	HS2K	HS2M	Unit
Typical thermal resistance(1)	$R_{\theta JA}$	54								°C/W
	$R_{\theta JC}$	16								
	$R_{\theta JI}$	7								

Notes:1. The thermal resistance from junction to ambient,case or mount,mounted on P.C.B with 8×8mm copper pads,2 OZ,FR4 PCB

Ratings and Characteristics Curves (T_A = 25°C unless otherwise noted)

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

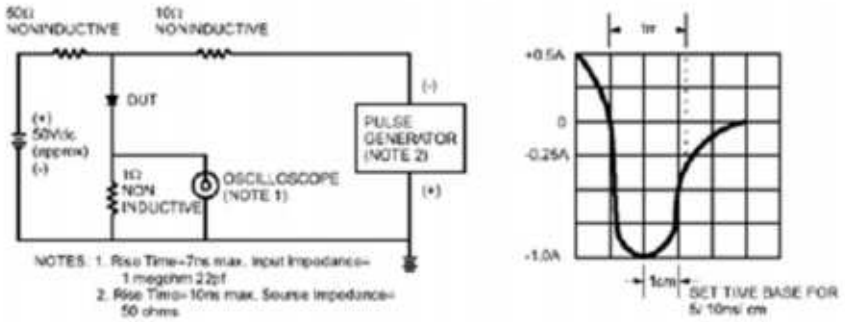


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

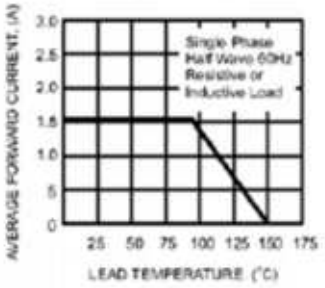


FIG.3- TYPICAL REVERSE CHARACTERISTICS

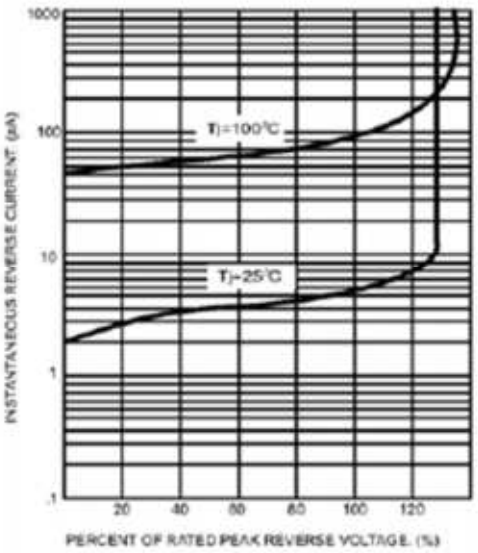


FIG.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

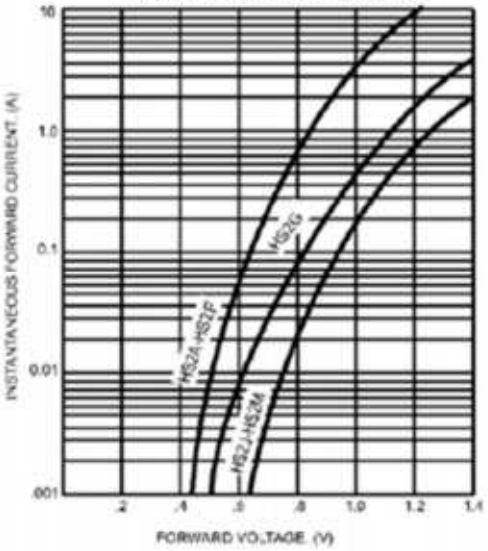


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

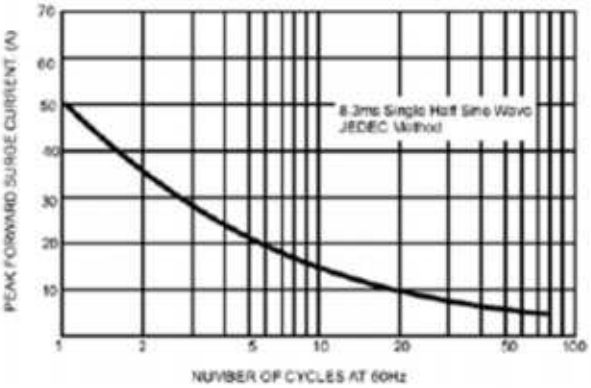
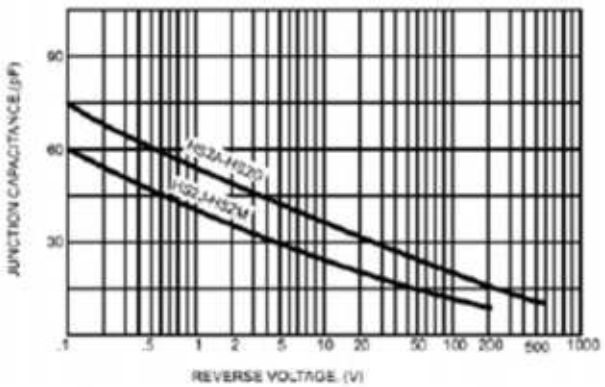


FIG.6- TYPICAL JUNCTION CAPACITANCE



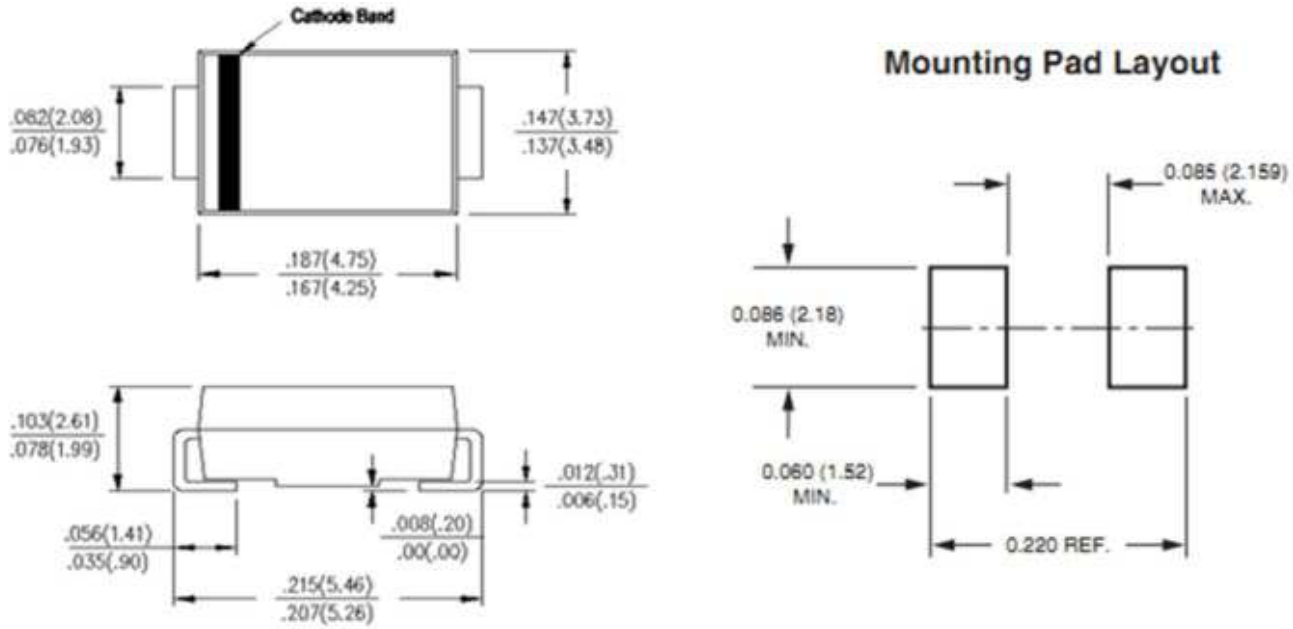
HS2A thru HS2M

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Package Outline Dimensions

in inches (millimeters)

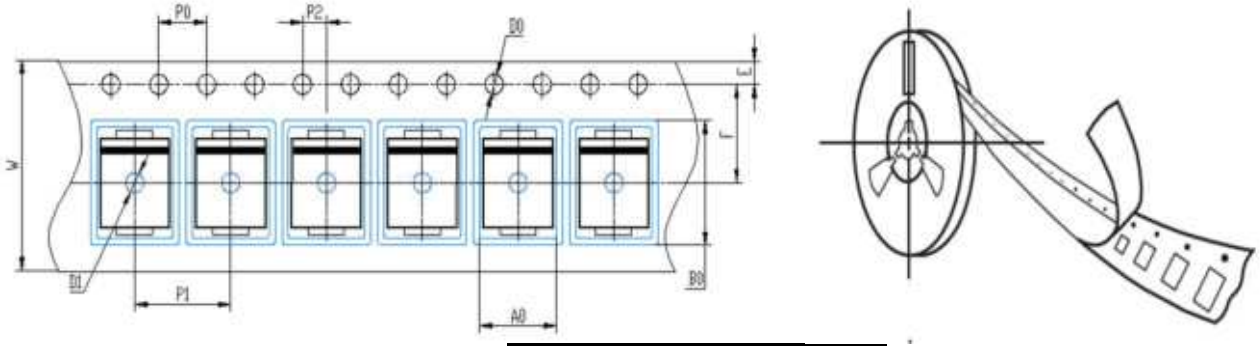
SMB (DO-214AA)



Packing Information

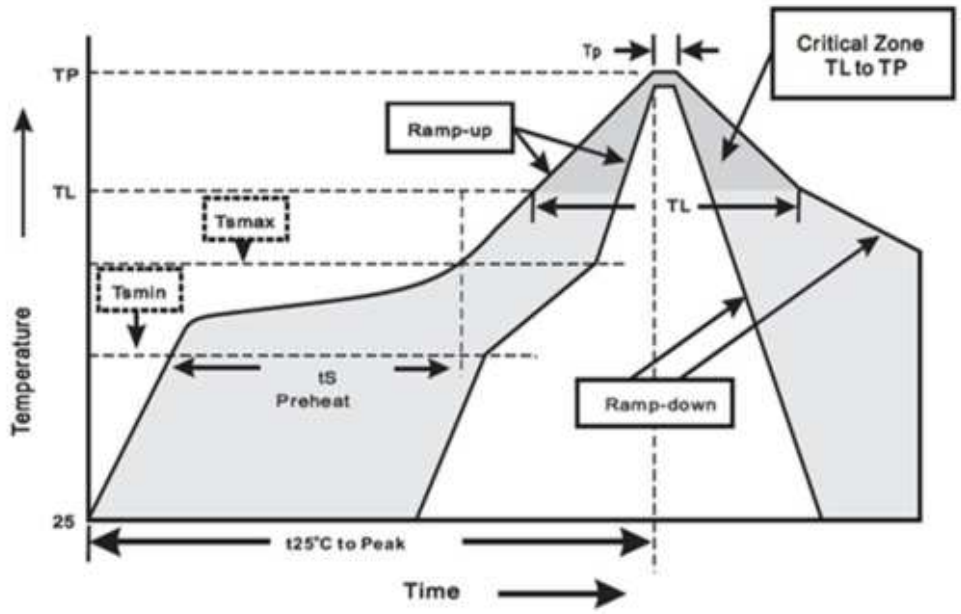
3000 pcs/Reel, 18 Reels/Box; 12mm Tape, 13" Reel

Tape & Reel Specification



Symbol	SMB(mm)
W	12±0.2
E	1.75±0.1
F	5.5±0.05
D0	1.5±0.1
D1	1.50 +0.1/-0
P0	4.0±0.1
P1	8.0±0.1
P2	2.0±0.05
A0	3.95±0.1
B0	5.74±0.1

Soldering Parameters



Reflow Condition		Lead–free assembly
Pre Heat	- Temperature Min (Ts(min))	150°C
	- Temperature Max (Ts(max))	200°C
	- Time (min to max) (ts)	60 – 180 secs
Average ramp up rate (Liquidus Temp (TL) to peak		3°C/second max
TS(max) to TL - Ramp-up Rate		3°C/second max
Reflow	- Temperature (TL) (Liquidus)	217°C
	- Time (min to max) (ts)	60 – 150 seconds
Peak Temperature (TP)		260+0/-5 °C
Time within 5°C of actual peak Temperature (tp)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (TP)		8 minutes Max.
Do not exceed		280°C